imall

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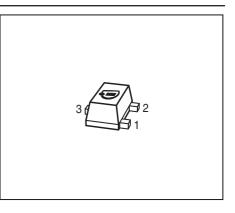




BFR193F

NPN Bipolar RF Transistor

- For low noise, high-gain amplifiers up to 2 GHz
- For linear broadband amplifiers
- $f_{\rm T}$ = 8 GHz, $NF_{\rm min}$ = 1 dB at 900 MHz
- Pb-free (RoHS compliant) and halogen-free product
- Qualification report according to AEC-Q101 available





ESD (Electrostatic discharge) sensitive device, observe handling precaution!

| Туре | Marking | Pin Configuration | | | Package |
|---------|---------|-------------------|-------|-------|---------|
| BFR193F | RCs | 1 = B | 2 = E | 3 = C | TSFP-3 |

Maximum Ratings at T_A = 25 °C, unless otherwise specified

| Parameter | Symbol | Value | Unit | |
|---------------------------------------|------------------|---------|------|--|
| Collector-emitter voltage | V _{CEO} | 12 | V | |
| Collector-emitter voltage | V _{CES} | 20 | | |
| Collector-base voltage | V _{CBO} | 20 | | |
| Emitter-base voltage | V _{EBO} | 2 | | |
| Collector current | I _C | 80 | mA | |
| Base current | I _B | 10 | | |
| Total power dissipation ¹⁾ | P _{tot} | 580 | mW | |
| $T_{\rm S} \le 72^{\circ}{\rm C}$ | | | | |
| Junction temperature | T _J | 150 | °C | |
| Storage temperature | T _{Stg} | -55 150 | | |

Thermal Resistance

| Parameter | Symbol | Value | Unit |
|--|-------------------|-------|------|
| Junction - soldering point ²⁾ | R _{thJS} | 135 | K/W |

 $^{1}T_{S}$ is measured on the collector lead at the soldering point to the pcb

²For calculation of R_{thJA} please refer to Application Note AN077 (Thermal Resistance Calculation)



| Parameter | Symbol | Values | | | Unit |
|---|----------------------|--------|------|------|------|
| | | min. | typ. | max. | |
| DC Characteristics | | | | | |
| Collector-emitter breakdown voltage | V _{(BR)CEO} | 12 | - | - | V |
| I _C = 1 mA, I _B = 0 | | | | | |
| Collector-emitter cutoff current | I _{CES} | - | - | 100 | μA |
| V _{CE} = 20 V, V _{BE} = 0 | | | | | |
| Collector-base cutoff current | I _{CBO} | - | - | 100 | nA |
| $V_{\rm CB}$ = 10 V, $I_{\rm E}$ = 0 | | | | | |
| Emitter-base cutoff current | I _{EBO} | - | - | 1 | μA |
| $V_{\rm EB}$ = 1 V, $I_{\rm C}$ = 0 | | | | | |
| DC current gain | h _{FE} | 70 | 100 | 140 | - |
| $I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, pulse measured | | | | | |

Electrical Characteristics at $T_A = 25^{\circ}$ C, unless otherwise specified



| Parameter | Symbol | Values | | 1 | Unit |
|---|---------------------------------|--------|------|------|------|
| | | min. | typ. | max. | |
| AC Characteristics (verified by random sampling) | | | | | |
| Transition frequency | f _T | 6 | 8 | - | GHz |
| <i>I</i> _C = 50 mA, <i>V</i> _{CE} = 8 V, <i>f</i> = 500 MHz | | | | | |
| Collector-base capacitance | C _{cb} | - | 0.63 | 1 | pF |
| V_{CB} = 10 V, <i>f</i> = 1 MHz, V_{BE} = 0, emitter grounded | | | | | |
| Collector emitter capacitance | C _{ce} | - | 0.25 | - | |
| V_{CE} = 10 V, f = 1 MHz, V_{BE} = 0, base grounded | | | | | |
| Emitter-base capacitance | C _{eb} | - | 2.25 | - | |
| $V_{\rm EB}$ = 0.5 V, f = 1 MHz, $V_{\rm CB}$ = 0 , | | | | | |
| collector grounded | | | | | |
| Minimum noise figure | NF _{min} | | | | dB |
| $I_{\rm C}$ = 10 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$, | | | | | |
| <i>f</i> = 900 MHz | | - | 1 | - | |
| <i>f</i> = 1.8 GHz | | - | 1.6 | - | |
| Power gain, maximum stable ¹⁾ | G _{ms} | - | 12.5 | - | dB |
| $I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$, | | | | | |
| $Z_{\rm L} = Z_{\rm Lopt}$, $f = 900 \rm MHz$ | | | | | |
| Power gain, maximum available ¹⁾ | G _{ma} | - | 19 | - | dB |
| $I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$, | | | | | |
| $Z_{\rm L} = Z_{\rm Lopt}$, $f = 1.8 {\rm GHz}$ | | | | | |
| Transducer gain | S _{21e} ² | | | | dB |
| $I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ =50 Ω , f = 900 MHz | | - | 14.5 | - | |
| <i>f</i> = 1.8 GHz | | - | 8.5 | - | |
| Third order intercept point at output ²⁾ | IP ₃ | - | 29 | - | dBm |
| V _{CE} = 8 V, <i>I</i> _C = 30 mA, <i>f</i> = 900 MHz, | | | | | |
| $Z_{\rm S} = Z_{\rm L} = 50 \ \Omega$ | | | | | |
| 1dB compression point at output ³⁾ | P _{-1dB} | - | 14.5 | - | 1 |
| $I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 Ω , | | | | | |
| f = 900 MHz | | | | | |

Electrical Characteristics at $T_A = 25^{\circ}$ C, unless otherwise specified

 ${}^{1}G_{\mathrm{ma}} = |S_{21} / S_{12}| \ (\mathrm{k} \cdot (\mathrm{k}^{2} \cdot 1)^{1/2}), \ \ G_{\mathrm{ms}} = |S_{21} / S_{12}|$

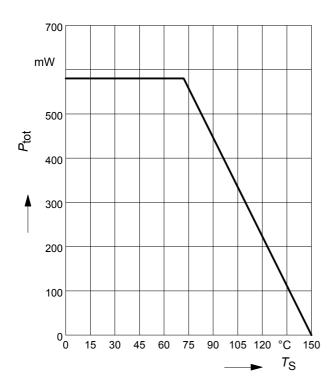
²IP3 value depends on termination of all intermodulation frequency components.

Termination used for this measurement is 50Ω from 0.1 MHz to 6 GHz

³DC current at no input power



Total power dissipation $P_{tot} = f(T_S)$

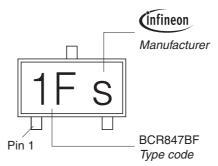




0.8±0.05

Package Outline 1.2 ± 0.05 0.2±0.05 0.55 ± 0.04 MAX **.2**±0.05 0.2±0.05 ° 1 2 0.2±0.05 0.15 ± 0.05 0.4±0.05 0.4±0.05 Foot Print 0.4 0.45

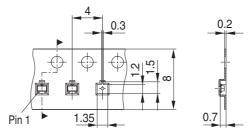




0.4

Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel



0.4



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